Diode Semiconductor Device - Page 1 of 1



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Inclosure Materia	1:
Glass	
Overall Length:	
Between 0.230 inc	hes and 0.300 inches
Terminal Length:	
Between 1.000 inc	hes and 1.500 inches
Overall Diameter:	
Between 0.085 inc	hes and 0.107 inches
Electrode Interna	Ily-electrically Connected To Case:
Cathode	
Mounting Method	I:
Terminal	
Features Provide	d:
Hermetically seale	d case
Semiconductor M	laterial:
Silicon	
Voltage Rating In	Volts Per Characteristic:
100.0 regulator v	oltage
Current Rating Po	er Characteristic:
3.00 milliamperes	source cutoff current pascal
Maximum Operat	ing Tempurature Per Measurement Point:
175.0 degrees cels	sius ambient air
Test Data Docum	ent:
81349-mil-s-19500) specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specificatio
format; excludes of	commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and	performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type Ar	nd Quantity:
2 uninsulated wire	lead
Specification Dat	a:
81349-mil-s-19500)/463 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	